NSN 5961-01-114-0707

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-114-0707 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.055 inches and 0.090 inches **Function For Which Designed:** Voltage regulator **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 6.20 milliamperes voltage regulator diode current and 19.00 milliamperes dc current in reverse breakdown region **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Product Name:** Semiconductor device, diode **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/117 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization:

NSN 5961-01-114-0707

Diode Semiconductor Device - Page 2 of 2



Mil-std (military Standard):

Mil-prf-19500 spec.